Plasma and Dry Micro/Nanotechnologies 2. Gas Kinetics

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- 2.1 Vapors and Gases
- 2.2 Maxwell-Boltzmann Distribution
- 2.3 Ideal-Gas Law
- 2.4 Knudsen Equation
- 2.5 Energy Stored in Gases
- 2.6 Units of Measurement
- 2.7 Mean Free Path
- 2.8 Knudsen number
- 2.9 Transport Properties
- p-V-T diagram, critical point, vapors versus gases, saturation vapor pressure
- Maxwell-Boltzmann distribution, mean speed, ideal gas law, Knudsen equation
- energy stored in molecules, equipartition theorem, heat capacity at constant volume and pressure
- standard conditions, units of sccm
- mean free path, molecular versus fluid flow (Knudsen number)
- transport of mass (diffusion), momentum (viscous shear) and energy (heat conduction)

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p-V-T diagram

The possible equilibrium states can be represented in **pressure-volume-temperature** (p-V-T) space for fixed amount of material (e.g. 1 mol = 6.02×10^{23}).



Lines = cuts through the p-V-T surface for fixed $T \Rightarrow$ relationship between p and V_m (molar volume).

Line a - b - c below the critical point (at T_2):

- point a: highest V (lowest p) vapor phase
- From point *a* to *b*: reducing $V \rightarrow$ increasing *p*
- point b: condensation begins
- from point b to c: V is decreasing at fixed p (b - c line is ⊥ to the p-T plane, p is called saturation vapor pressure p_v or just vapor pressure)
- point c: condensation completed

If *V* is abruptly decreased in b - c transition *p* would be pushed above the line $b - c \Rightarrow$ **non-equilibrium supersaturated vapors**. Supersaturation is an important drivign force in the nucleation and growth of thin films.

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p-V-T diagram

It is important to distinguish between the behaviors of vapors and gases:



- vapors: can be condensed to liquid or solid by compression at fixed *T*, i.e. below critical point defined by p_c, V_c and T_c
- ▶ gases: monotonical decrease of *V* upon compression \Rightarrow no distinction between the two phases; or sometimes a vapor that is not condensable under conditions encountered in thin-film deposition: p T

 $p \leq p_{\rm atm}, \, T \geq T_{\rm room}$

Surfaces "liquid-vapor", "solid-vapor" and "solid-liquid" are perpendicular to the p-T plane \Rightarrow their projection on that plane are lines.



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p-T diagram			
Ρ	solid	Equilibrium CRITICAL POINT vaporization	



- triple point: from triple line ⊥ to p-T plane
- ▶ below T of triple point: liquid-phase region vanishes ⇒ condensation directly to the solid phase, vaporization in this region is sublimation
- pressure along borders of vapor region is vapor pressure p_v

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p-T diagram			
Ρ	solid solid	CRITICAL POINT	



- vapor pressure p_v increases exponentially with T up to p_c
- ▶ p_c is well above 1 atm \Rightarrow deposition of thin films is performed at $p \ll p_c$, either $p > p_v$ (supersaturated vapors) or $p < p_v$
- ▶ first two steps in the deposition (source supply and transport to substrate) should be carried out at p < p_v to avoid condensation
- condensation should be avoided also during compression in vacuum pumps

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2.2 Maxwell-Boltzman	n Distribution		

Distribution of random velocities \vec{V} in equilibrium state

$$f(\vec{V}) = n \left(\frac{m}{2\pi k_{\rm B}T}\right)^{3/2} \exp\left(-\frac{mV^2}{2k_{\rm B}T}\right)$$
(1)

where $k_{\rm B} = 1.38 \times 10^{-23}$ m² kg s⁻² K⁻¹ (or J K⁻¹) is the Boltzmann constant, *n*, *T* and *m* are particle density, temperature and mass, respectively.

If the drift velocity is zero we do not need to distinguish between the velocity and random velocity, i.e. $\vec{v} \equiv \vec{V}$.

Maxwell-Boltzmann distribution is isotropic \Rightarrow *F*(*v*) distribution of speeds *v* \equiv $|\vec{v}|$ can be defined by integration of *f*(*v*) in spherical coordinates

$$F(v)dv = \int_0^\pi \int_0^{2\pi} f(v)v^2 \sin\theta d\phi d\theta dv$$
(2)

resulting in

$$F(v) = 4\pi v^2 n \left(\frac{m}{2\pi k_{\rm B}T}\right)^{3/2} \exp\left(-\frac{mv^2}{2k_{\rm B}T}\right)$$
(3)

Mean (Average) Speed, Molecular Impingement Flux



Mean speed:

$$\langle v \rangle = v_{\rm av} = \frac{1}{n} \int_0^\infty F(v) v dv = \sqrt{\frac{8k_{\rm B}T}{\pi m}}$$
(4)

or

$$v_{\rm av} = \sqrt{\frac{8RT}{M}} \tag{5}$$

using molar mass $M = mN_A$ in kg/mol and gas constant

$$R = k_{\rm B} N_{\rm A} = 8.31 \, {\rm Jmol}^{-1} {\rm K}^{-1}$$

where $N_{\rm A} = 6.02 \times 10^{23} \mbox{ mol}^{-1}$ is Avogadro's number

Root-mean-square (rms) speed:

$$v_{\rm rms} = \sqrt{\frac{1}{n} \int_0^\infty F(v) v^2 dv} = \sqrt{\frac{3k_{\rm B}T}{m}} \quad (6)$$

The most probable speed $v_{\rm p}$:

$$\left(\frac{dF(v)}{dv}\right)_{v=v_{\rm p}} = 0 \Rightarrow v_{\rm p} = \sqrt{\frac{2k_{\rm B}T}{m}} \quad (7)$$

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2.3 Ideal-Gas Law			

From the definition of pressure for ideal gas (not necessary to consider pressure tensor but only scalar pressure)

$$\rho = \frac{1}{3}mn\langle \vec{V}_x^2 + \vec{V}_y^2 + \vec{V}_z^2 \rangle = \frac{1}{3}mn\langle \vec{V}^2 \rangle = m \int_V V^2 f(V) \, d^3 V.$$
(8)

The ideal-gas law is obtained by integration of (8) using Maxwell-Boltzmann distribution:

$$\rho = nk_{\rm B}T$$
 or $\frac{\rho V}{T} = Nk_{\rm B}$ (9)

where N is the number of particles.

Chemists are used to work in molar amounts ($N_{\rm A} = 6.022 \times 10^{23} \text{ mol}^{-1}$):

- molar concentration $n_{\rm m} = n/N_{\rm A} \Rightarrow p = n_{\rm m}RT$
- number of moles $N_{\rm m} = N/N_{\rm A} \Rightarrow p = N_{\rm m} RT/V$
- molar volume $V_{\rm m} = V/N_{\rm A} \Rightarrow \rho = RT/V_{\rm m}$

The ideal gas is obeyed if

- the volume of molecules in the gas is much smaller than the volume of the gas
- the cohesive forces between the molecules can be neglected.

Both assumptions are fulfilled for low $n \Rightarrow$ always fulfilled for thin film deposition from the vapor phase ($T \ge T_{\rm room}$ and $p \le p_{\rm atm}$), i.e. well away from the critical point (most materials $p_{\rm c} \gg 1$ atm or if not $T_{\rm c} \ll 25$ °C)

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2.4 Knudsen Equation	1		

The **molecular impingement flux** at a surface is a fundamental determinant of film deposition rate:

$$\Gamma = n \langle v \cos \theta \rangle = \int_0^\infty \int_0^{\pi/2} \int_0^{2\pi} f(v) v^3 \cos \theta \sin \theta d\phi d\theta dv$$
(10)

Substituting Maxwell-Boltzmann distribution

$$\Gamma = n \left(\frac{k_{\rm B}T}{2\pi m}\right)^{1/2} = \frac{1}{4} n v_{\rm av} \tag{11}$$

and using ideal gas law

$$\Gamma = \rho \left(\frac{1}{2\pi kTm}\right)^{1/2} = \rho N_A \left(\frac{1}{2\pi RTM}\right)^{1/2}$$
(12)

where $M = mN_A$ and $R = kN_A$ (*M* is molar mass)

Calculate molecular impinging flux for CO₂ molecules (44 a. u., 330 pm), 25 $^{\circ}$ C, 10⁻³ Pa. Considering the molecule diameter of 330 pm calculate monolayer deposition rate considering all impinging molecules stick to the surface.

2.5 Energy Forms Stored by Molecules

Molecules can store energy in various forms. Their energetic states are quantized (spacing between energy levels ΔE)

- electronic excitations ΔE_e is highest, transitions between different electronic states are possible only for extremely high T or collision with energetic particle
- vibrational excitations energy levels correspond to different vibration modes of the molecule, Δ*E*_v ≈ 0.1 eV (1 eV = 11 600 K)
- $\blacktriangleright\,$ rotational excitations different rotational modes of the molecule, $\Delta E_{\rm r} \approx 0.01~eV$
- ► translational energy above performed description of molecular random motion $E_{\rm t} = 1/2mV^2$, no details of inner molecule structure are considered, $\Delta E_{\rm t}$ negligible at ordinary *T*.



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2.5 Energy Content of Gas

From definition of absolute temperature - the mean thermal energy kT/2 belongs to each translational degree of freedom and molecular translation energy is

$$E_{\rm t} = \frac{3}{2} k_{\rm B} T \tag{13}$$

⇒ equipartition theorem of classical statistical mechanics. Classical statistical treatment assumes very close quantized energy levels of molecules, i.e. approximated as a continuum. It is a good assumption for translational energy when $T \gg 0$ K.

- ► For atomic gases, *E*_t is total kinetic energy content.
- For molecular gases, E_r is added at ordinary T and E_v at very high T:

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Molar heat capacity at constant volume c_V (for molecular gas) [J/(mol.K)] - increase of total kinetic energy for increasing T:

$$c_{\rm V} = \frac{\mathrm{d}E_{\rm m}}{\mathrm{d}T} N_{\rm A} = \frac{\mathrm{d}(E_{\rm t} + E_{\rm r} + E_{\rm v})}{\mathrm{d}T} N_{\rm A}$$
(14)

for atomic gases

$$c_{\mathrm{V}}=rac{3}{2}R=rac{3}{2}kN_{\mathrm{A}}$$

for small diatomic molecules at room T

$$c_{
m V}=rac{5}{2}R$$

- two rotational degrees of freedom are excited but vibrational ones are not

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2.5 Energy Content of Gas - at constant pressure

The heat capacity of any gas is larger when measured at constant pressure c_p - heat input is doing p d V work on the surroundings in addition to adding kinetic energy to the molecules:

$$c_{\rm p} = c_{\rm V} + R \tag{15}$$

We can write from thermodynamics

$$c_{\rm V} = \left(\frac{\partial U_{\rm m}}{\partial T}\right)_V \tag{16}$$

where U_{m} is internal energy per mol $\mathit{U}_{\mathrm{m}}=\mathit{E}_{\mathrm{m}}\mathit{N}_{\mathrm{A}}$ and

$$c_{\rm p} = \left(\frac{\partial H_{\rm m}}{\partial T}\right)_{\rho} \tag{17}$$

where ${\it H}_{\rm m}$ is enthalpy per mol ${\it H}_{\rm m}={\it U}_{\rm m}+{\it \rho}{\it V}_{\rm m} \Rightarrow$

$$\left(\frac{\partial H_{\rm m}}{\partial T}\right)_{\rho} = \left(\frac{\partial U_{\rm m}}{\partial T}\right)_{\rho} + \rho \left(\frac{\partial V_{\rm m}}{\partial T}\right)_{\rho} \tag{18}$$

giving $\textit{c}_{\mathrm{p}}=\textit{c}_{\mathrm{V}}+\textit{R}$

2.6 Units of Measurement

SI units?! 1 Torr = 133 Pa = 1 mm Hg 1 bar = 750 Torr = 1.0×10^5 Pa = 0.99 atm (standard atmosphere) The "standard" conditions of *T* and *p* (stp) are 0°C and 1 atm (760 Torr). From ideal gas law at stp $V_{\rm m} = 22400$ cm³. These conditions are different from standard conditions to which thermodynamic data are referenced: 25°C and 1 bar.

In gas supply monitoring - the term "mass" flow rate measured in standard cm³ per minute (second or liters per minute): sccm, sccs, slm. Standard means 0°C and 1 atm.

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2.7 Mean Free Path





Unless *T* is extremely high, *p* is the main determinant of *I*, $I \approx 1/p$.

Mean free path

$$\lambda = \frac{1}{\sigma_{\rm m} n_{\rm g}} \tag{19}$$

electrons travelling through gas: electrons are much smaller than molecules \Rightarrow collision cross section σ_m is just projected area of the gas molecule

$$\lambda_{\rm e} = \frac{1}{\pi/4a^2n_{\rm g}} \tag{20}$$

It's approximation, σ_m is function of el. energy

ions travelling through gas: similar diameter

$$\lambda_{\rm i} = \frac{1}{\pi a^2 n_{\rm g}} \tag{21}$$

■ molecule-molecule collisions: "target" particles are not steady (comparable velocities) ⇒ mean speed of mutual approach is √2v_{av} rather than v_{av} (on average they approach each other at 90°) ⇒ it shortens / by √2

$$\lambda_{\rm m} = \frac{1}{\sqrt{2\pi a^2 n_{\rm g}}} \tag{22}$$

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2.8 Knudsen number

It is worth remembering that the mean free path at 1 Pa and room T is about 1 cm for small molecules.

The order of magnitude of *I* is very important in film deposition, because it determines whether the process is operating in the high-vacuum or the fluid-flow regime. The regime is determined by the **Knudsen number**:

$$Kn = \lambda/L$$
 (23)

where *L* is a characteristic dimension in the process, e.g. distance between the source and the substrate, λ is the mean free path.

- ► For *Kn* > 1, the process is in high-vacuum regime (molecular flow regime).
- For $Kn \ll 0.01$, the process is in **fluid flow regime**.

Intermediate values of Kn constitute a transition regime where the equations applicable to either of limiting regimes are not strictly valid.

Plasma processes often operate in the transition regime. High-vacuum processes require $p < 10^{-2}$ Pa for typical chamber sizes to ensure Kn > 1.

2.9 Transport Properties

- quantify the rate of hangood of mans (diffusion) momentum (viscous sheare) / through a energy (head conduction)) fluid (we mean gaseous Transpord to be discussed Voccurs by random molecular molicin through a gas which has no buck flow in the direction of the hampord. man and head can be also hamported & bulk flow but it is not discussed here. Table 2.1 (p. 26) rummaures the quartilies and ego. It instude above al. entrend (fine of the trange, of charge) because it's helpful analogy. Transport is always described by an eq. of the form (flux of A) = - (menorlional. Jaclor) × (grad in general form is 3D but we will give it in 1D for simplicity. density Erample for electrical current fx : jx (H/m2) = S. dv _ gred. of el. conductivity el. potential (welage Viller A A familiar others law Vim = p el. resistivity

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18/26

2.8 Transport Properties - Overview

		Proportionality fa	ictor
Fransported quantity	- Describing equation	Derivation from elementary kinetic theory	Typical value at 300 K, 1 atm
Mass	Diffusing flux = $J_A\left(\frac{mc}{cm^2 \cdot s}\right) = -D_{AB}\left(\frac{dn_A}{dx}\right)$ (Fick's law)	$\begin{split} \text{Diffusivity} = \\ \text{D}_{\text{AB}}\!\left(\!\frac{\text{cm}^2}{\text{s}}\!\right) = & \frac{1}{4} \hat{c} \hat{l} \propto \frac{T^{7/4}\!\left(\frac{1}{M_{\text{A}}} + \frac{1}{M_{\text{B}}}\right)^{1/2}}{p(a_{\text{A}} + a_{\text{B}})^2} \end{split}$	Ar-Ar: 0.19 cm ² /s Ar-He: 0.72
Momentum	Shear stress = $\tau(N/m^2) = \eta \frac{du}{dx}$	Viscosity = $\eta(\text{Poise})^{\dagger} = \frac{1}{4} \text{nm} \bar{c} l \propto \frac{\sqrt{MT}}{a^2}$	Ar: 2.26×10 ⁻⁴ Poise [†] He: 2.02×10 ⁻⁴
Energy (heat)	Conductive heat flux = $\Phi\left(\frac{W}{cm^{2}}\right) = -K_{T}\frac{dT}{dx}$ (Fourier's law)	$\begin{split} & \text{Thermal conductivity} = \\ & K_T\!\left(\frac{W}{cm\cdot K}\right) = \frac{1}{2} n\!\left(\frac{c_\nu}{N_A}\right) \! \hat{c} l \approx \sqrt{\frac{T}{M}} \frac{c_\nu}{\alpha^2} \end{split}$	Ar: 0.176 mW/cm·K He: 1.52
Charge	Current density = $j\left(\frac{A}{cm^2}\right) = \frac{-1}{\rho} \frac{dV}{dx} = -s \frac{dV}{dx}$ (Ohm's law)		in Dy an Andrew An Dy a function in Dy a func- tion Dy a func- Dy a func

Table 2.1 Gas transport properties from the book by Donald L. Smith, Thin-Film Deposition: Principles & Practice, McGraw-Hill 1995.

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2.8.1 Diffusion			
$\begin{array}{c} \mathbf{A} \mathbf{B} \mathbf{O} \\ \mathbf{O} \mathbf{O} \mathbf{O} \mathbf{O} \mathbf{O} \\ \mathbf{O} \mathbf{O} \mathbf{O} \mathbf{O} \\ \mathbf{O} \mathbf{O} \mathbf{O} \end{array}$	Molecular diffusion is demonstrat A (black) and B (white). Consider molecules A is decreasing from <i>r</i> <i>x</i> -direction over a distance of <i>one</i> Diffusion of A occurs in the dir	ted using mixture of molecule r, the concentration of black n_A to $n_A - \Delta n_A$ in the remean free path $\lambda \Rightarrow$ rection of decreasing n_A .	s
A rough estimate of diffusion imaginary slab of thickness 2	flux can be made by calculating the flux can be made by calculating the λ (/ in D. Smith book), using	he net flux through an	
	$\Gamma = \frac{1}{4} n \langle v \rangle \text{ where } \langle v \rangle = \sqrt{\frac{8kT_{\rm B}}{\pi m}}$	-	
for the fluxes in opposite dire	ections \downarrow and $\uparrow \Rightarrow \Gamma_{\rm A} = \Gamma(x) - \Gamma(x)$	$(x + \lambda) = 1/4\Delta n_{\rm A} \langle v \rangle$	

Since $\Delta n_{\rm A} = \lambda \frac{-{\rm d}n_{\rm A}}{{\rm d}x}$, we have $\Gamma_{\rm A} = -\frac{1}{4} \langle v \rangle \lambda \frac{{\rm d}n_{\rm A}}{{\rm d}x} \Rightarrow$

$\Gamma_{\rm A} = -D_{\rm AB} rac{{\rm d} n_{\rm A}}{{\rm d} { m x}}$ Fik's law, $D_{\rm AB}$ diffusion coefficient of A through B

Inserting expression for $\langle v \rangle$ and molecule-molecule mean free path $\lambda = \frac{1}{\sqrt{2\pi}\sigma^2 n}$ we find

Empirically, it should be $T^{7/4}$, and $D_{\rm AB} \sim \frac{T^{3/2}}{\sqrt{m}a^2n}$ m and a are averaged to account for A-B mixture, see next slide.

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2.8.1	Diffusion				
	Jypund value ad	$D_{RB} = \frac{m^2}{5}$ 300K, Jalon	$= \frac{T^{*4}}{P} \left(\frac{1}{m_{A}}\right)^{*} \left(\alpha_{A} + \frac{1}{P} - Ar\right)^{*} O_{A}$ $= \frac{T^{*4}}{P} \left(\alpha_{A} + \frac{1}{P} - Ar\right)^{*} O_{A}$	$\frac{+\frac{1}{m_{B}}}{a_{B}}^{1/2} \frac{but}{b b t}$ $\frac{but}{b b t}$ $\frac{but}{b t}$	DAB has anyway I angeway inang micles
	and dyindeme of empirially determin of a fuelor two Dependence of D. lower than 1a processes => 1 withen p is re diffusion no lon wall in molecu in the gas pla	Dog on p, T ad values and our on p is part Im by many on DAB · duesd so far the eger coours. Indu	can be extrap expression I coularly impor- colors of mag hat Km > 1 (moleculas file rad, molecule ut encounter	delect using S(p,T) with an land, since it a mitude in dep $(Kn = \frac{\lambda}{L})$ $ne^{-regime)}$ S have from un ing each other	uracy an be ws.) all lo
	in the g				

2.8.2 Viscosity

f yas a vincosity is the result of molecular momentum transport along a gradient in bulk flow velocity u. / $\vec{u} = \langle \vec{v} \rangle$ (drift velocity)

The u gradient is along the x axis, purpendicular to the Tris rituation is encountered in fluid flowwhenever the flow hears approaches a boundary (u must go to toro) superimposed is the random mole molies at velocity (v).

The random motion causes molecules to continually even up and down between rearres separated by λ . Those moving upward will gain mementum more upon colliding with molecules in the porter flow dream => drag force on the flow dream at x (spomulacief all?)

2.8.2 Viscosity

Timilarly, there moving downward will evert an accelerating force on the viskozní tečne napětí slower flow tream at X+X These forces are equal and opposite in a deady-date - viscous thear tress T (N/m2) = rate of momentum transfer per unit area 1 por 2 => T = molecular flux × momentum gain/loss per molecule $\mathcal{T} = \frac{1}{4}n\langle w \rangle \cdot m \, \frac{\lambda}{w} \frac{du}{dx} = \eta \frac{du}{dx}$ viscosily { kg.s = N.S = Pa.s} $=\frac{1}{4}n_{\chi}\sqrt{\frac{3kT}{\pi_{m}}}\cdot m\cdot \frac{1}{\sqrt{217}a^{2}n_{\chi}}\sim \frac{\sqrt{T.m}}{a^{2}}$ Juba . Jelance Two surprises : 1. of I will T (generile to liquid behaviour) 2. n = fancl. (p) as in the case of diffusion, viscosity has no meaning for Kn >1

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2.8.3 Heat transfer

Gaseous heat conduction occurs by transfer of energy in molecular collisions downward along a gradient in molecular kinetic energy $E_{\rm m}$. Equation for the **heat flux** Φ is analogous to that for momentum transfer, with $m\Delta u$ replaced by $2\Delta E_{\rm m}$

$$\Phi = \frac{1}{4} n \langle v \rangle 2\lambda \frac{\mathrm{d}E_{\mathrm{m}}}{\mathrm{d}x}$$
(24)

with the units $J/(s.m^2)$ or W/m^2 .

We can substitute ${\cal T}$ for ${\it E}_{\rm m}$ using Eq. (14) for molar heat capacity at constant volume

$$\frac{\mathrm{d}E_{\mathrm{m}}}{\mathrm{d}x} = \frac{\mathrm{d}E_{\mathrm{m}}}{\mathrm{d}T}\frac{\mathrm{d}T}{\mathrm{d}x} = \frac{c_{\mathrm{V}}}{N_{\mathrm{A}}}\frac{\mathrm{d}T}{\mathrm{d}x}$$
(25)

Thus, we obtain Fourier's law

$$\Phi = -\kappa_{\rm T} \frac{{\rm d}T}{{\rm d}x} \tag{26}$$

where **thermal conducitivty** $K_{\rm T} \sim \sqrt{T/m} c_{\rm V}/a^2$. Small, light molecules generally have higher $K_{\rm T}$ although this trend is sometimes reversed by the higher $c_{\rm V}$ of more complex molecules, which have more rot. and vibr. modes of energy storage.

Like η , K_T is independent of p for the same reason: as $p \downarrow$, molecular flux $\Gamma \downarrow$ but $\lambda \uparrow$. However, the situation changes for so low p that the gas is in molecular regime (see next slides).

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2.8.3 Heat transfer - molecular regime

Heat transfer by gas conduction between two parallel plates:



... common situation in the film deposition, where one plate is a heated platform at temperature $T_{\rm h}$, and the other is a substrate being raised to $T_{\rm s}$ by the heat transfer from the platform. For the gap distance *b*, the Knudsen number is $Kn = \lambda/b$.

At the higher *p* where $Kn \ll 1$ (fluid flow), the heat flux is (using $K_{\rm T} \sim \sqrt{T/m} c_{\rm V}/a^2$)

$$\Phi = -\kappa_{\rm T} \frac{{\rm d}T}{{\rm d}x} = \frac{\kappa_{\rm T}}{b} (T_{\rm h} - T_{\rm s})$$
⁽²⁷⁾

For Kn > 1 (molecular flow), gas molecules are bouncing back and forth from plate to

plate without encountering any collisions \Rightarrow use of $K_{\rm T}$ (bulk fluid property) is no longer appropriate. Instead, the heat flux between the plates is proportional to the flux of molecules across the gap (Γ) times the heat carried per molecule (using Eq. (25)):

$$\Phi = \Gamma \gamma' \frac{c_{\rm V}}{N_{\rm A}} (T_{\rm h} - T_{\rm s}) \equiv h_{\rm c} (T_{\rm h} - T_{\rm s})$$
(28)

where γ' is the thermal accommodation factor (\approx unity except for He) and h_c is the heat transfer coefficient (W K/m²) given as $h_c = \sqrt{N_A/(2\pi R)} p/\sqrt{mT} \gamma' c_V$

Note that h_c appears, rather than K_T , whenever heat transfer is taking place across an interface rather than through a bulk fluid or other material.

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25 / 26

2.8.3 Heat transfer - heat transfer to substrate

There are two fundamental difference between the heat flux in the case of fluid $Kn \ll 1$ and molecular Kn > 1 regimes:

- Φ is inversely proportional to b for fluid whereas independent of b for molecular regime
- Φ is independent of p for fluid whereas proportional to p for molecular regime

One important conclusion which can be drawn for low p is that the heat transfer to a substrate from a platform can be increased by increasing p, but only if the gap is kept small enough that Kn > 1.

Helium is often chosen to improve the heat transfer because of its high $K_{\rm T}$, but in fact it is not the best choice when Kn > 1 because of the thermal accommodation factor in Eq. (28) - for discussion of γ' see the next slide.



From Eq. (28), the best choice for a heat-transfer gas is one having low molecular mass to give high Γ , while also having many rotational modes to give high $c_{\rm V}$. Choices will usually be limited by process chemistry.

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26/26

2.8.3 Heat transfer - thermal accommodation coefficient

In molecular flow regime Kn > 1 (right figure), consider the molecule approaching the heated platform.



It has the temperature $T_{\rm rs}$ acquired when reflected from the substrate. Upon being reflected from the platform, it will have temperature $T_{\rm rh}$. The **thermal accommodation coefficient** γ is defined as

$$\gamma = \frac{T_{\rm rs} - T_{\rm rh}}{T_{\rm rs} - T_{\rm h}}.$$
(29)

It represents the degree to which the molecule accommodates itself to the temperature $\mathcal{T}_{\rm h}$ of the surface from which it is reflected.

For most molecule-surface combinations, γ is close to unity, but for He it is 0.1–0.4, depending on the surface.

If γ is less than unity and is the same at both surfaces, the overall reduction in the heat flux represented by γ' is

$$\gamma' = \frac{\gamma}{2 - \gamma} \tag{30}$$